

# 4V Drive Pch MOSFET

## UM6J1N

### ●Structure

Silicon P-channel MOSFET

### ●Features

- 1) Two RSU002P03 transistors in a single UMT package.
- 2) The MOSFET elements are independent, eliminating mutual interference.
- 3) Mounting cost and area can be cut in half.

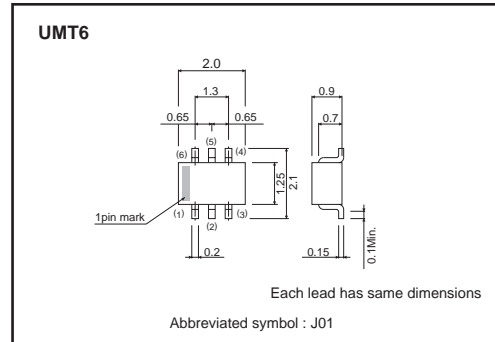
### ●Applications

Switching

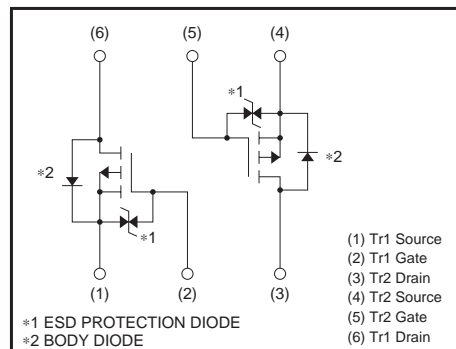
### ●Packaging specifications

Type	Package	Taping
	Code	TN
	Basic ordering unit (pieces)	3000
UM6J1N		○

### ●Dimensions (Unit : mm)



### ●Inner circuit



### ●Absolute maximum ratings (Ta=25°C)

<It is the same ratings for Tr1 and Tr2.>

Parameter	Symbol	Limits	Unit
Drain-source voltage	$V_{DSS}$	-30	V
Gate-source voltage	$V_{GSS}$	$\pm 20$	V
Drain current	Continuous	$I_D$	$\pm 0.2$ A
	Pulsed	$I_{DP}^{*1}$	$\pm 0.4$ A
Total power dissipation	$P_D^{*2}$	150	mW / TOTAL
		120	mW / ELEMENT
Channel temperature	$T_{ch}$	150	°C
Range of storage temperature	$T_{stg}$	-55 to +150	°C

\*1  $P_w \leq 10\mu s$ , Duty cycle  $\leq 1\%$

\*2 Each terminal mounted on a recommended land

### ●Thermal resistance

Parameter	Symbol	Limits	Unit
Channel to ambient	$R_{th(ch-a)}^{*}$	833	°C/W / TOTAL
		1042	°C/W / ELEMENT

\* Each terminal mounted on a recommended land

●Electrical characteristics (Ta=25°C)

<It is the same characteristics for Tr1 and Tr2.>

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I <sub>GSS</sub>	-	-	±10	μA	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V
Drain-source breakdown voltage	V <sub>(BR) DSS</sub>	-30	-	-	V	I <sub>D</sub> = -1mA, V <sub>GS</sub> =0V
Zero gate voltage drain current	I <sub>DSS</sub>	-	-	-1	μA	V <sub>DS</sub> = -30V, V <sub>GS</sub> =0V
Gate threshold voltage	V <sub>GS(th)</sub>	-1.0	-	-2.5	V	V <sub>DS</sub> = -10V, I <sub>D</sub> = -1mA
Static drain-source on-state resistance	R <sub>DS(on)</sub> *	-	0.9	1.4	Ω	I <sub>D</sub> = -0.2A, V <sub>GS</sub> = -10V
		-	1.4	2.1	Ω	I <sub>D</sub> = -0.15A, V <sub>GS</sub> = -4.5V
		-	1.6	2.4	Ω	I <sub>D</sub> = -0.15A, V <sub>GS</sub> = -4V
Forward transfer admittance	Y <sub>fs</sub>  *	0.2	-	-	S	V <sub>DS</sub> = -10V, I <sub>D</sub> = -0.15A
Input capacitance	C <sub>iss</sub>	-	30	-	pF	V <sub>DS</sub> = -10V
Output capacitance	C <sub>oss</sub>	-	4	-	pF	V <sub>GS</sub> =0V
Reverse transfer capacitance	C <sub>rss</sub>	-	5	-	pF	f=1MHz
Turn-on delay time	t <sub>d(on)</sub> *	-	8	-	ns	V <sub>DD</sub> ≐ -15V
Rise time	t <sub>r</sub> *	-	5	-	ns	I <sub>D</sub> = -0.15A
Turn-off delay time	t <sub>d(off)</sub> *	-	30	-	ns	V <sub>GS</sub> = -10V
Fall time	t <sub>f</sub> *	-	40	-	ns	R <sub>L</sub> ≐ 100Ω R <sub>G</sub> =10Ω

\* Pulsed

●Body diode characteristics (source-drain)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V <sub>SD</sub> *	-	-	-1.2	V	I <sub>S</sub> = -0.1A, V <sub>GS</sub> =0V

\*Pulsed

●Electrical characteristic curves

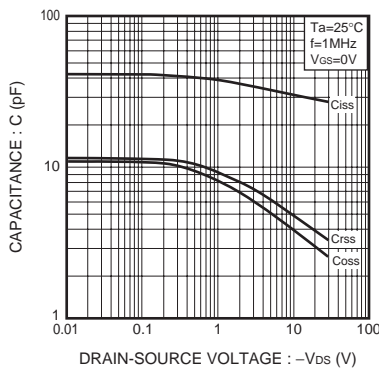


Fig.1 Typical Capacitance vs. Drain-Source Voltage

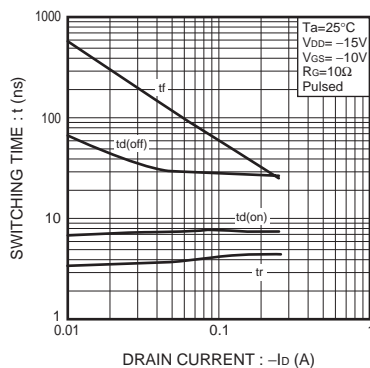


Fig.2 Switching Characteristics

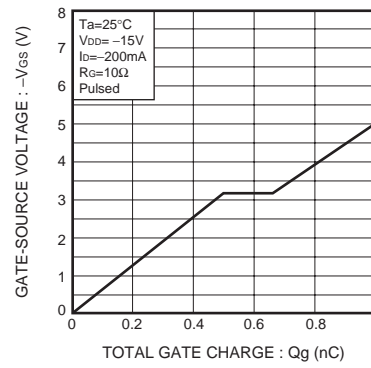


Fig.3 Dynamic Input Characteristics

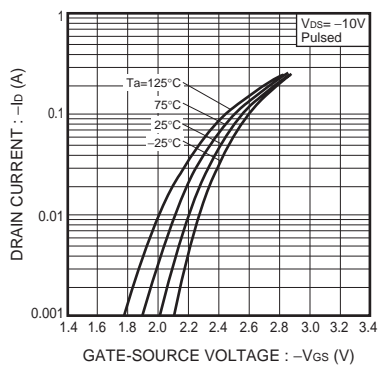


Fig.4 Typical Transfer Characteristics

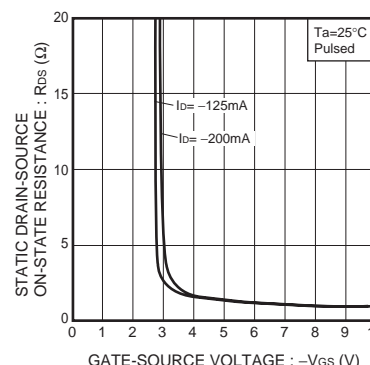


Fig.5 Static Drain-Source On-State Resistance vs. Gate-Source Voltage

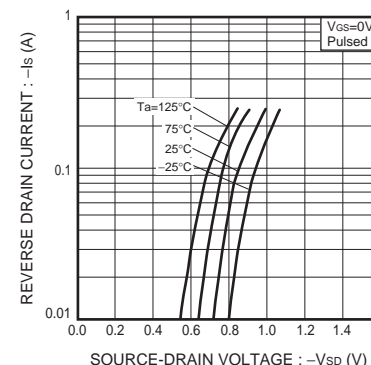


Fig.6 Reverse Drain Current vs. Source-Drain Voltage

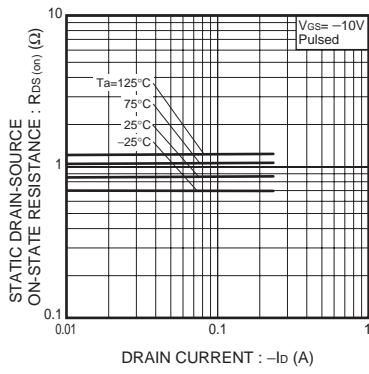


Fig.7 Static Drain-Source On-State Resistance vs. Drain Current ( I )

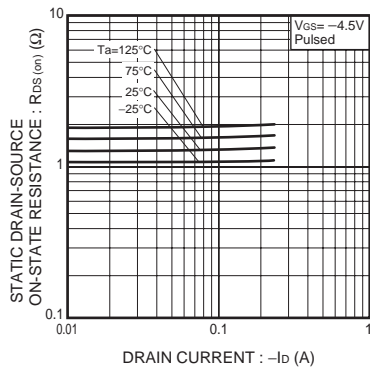


Fig.8 Static Drain-Source On-State Resistance vs. Drain Current ( II )

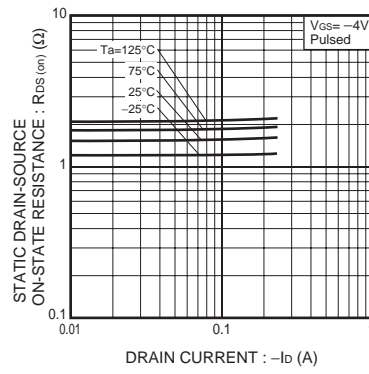


Fig.9 Static Drain-Source On-State Resistance vs. Drain Current ( III )

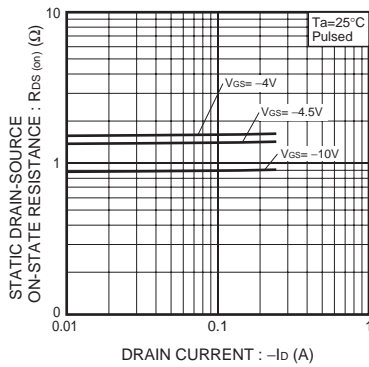


Fig.10 Static Drain-Source On-State Resistance vs. Drain Current ( IV )

●Notice

This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

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